

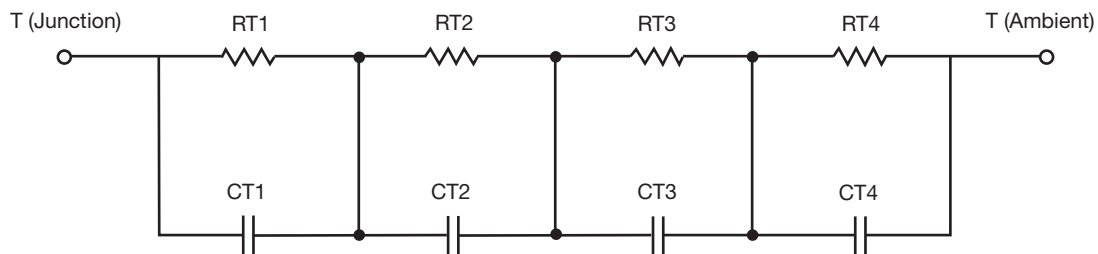
R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in PSpice, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the PSpice simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the PSpice Platform".

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	20.0863	216.4569m	n/a
RT2	10.8636	754.9670m	n/a
RT3	4.2288	186.1504m	n/a
RT4	29.8213	542.4257m	n/a
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	1.1400	288.8781u	n/a
CT2	98.3500m	4.8205m	n/a
CT3	5.1471m	30.7426u	n/a
CT4	4.1972	1.4187m	n/a

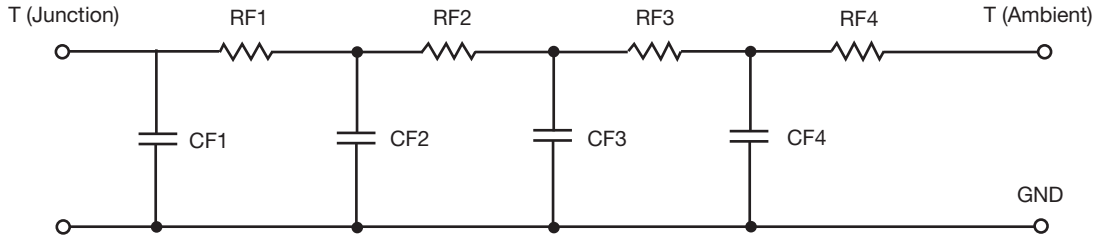
Note

- n/a indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



R-C THERMAL MODEL FOR FILTER CONFIGURATION



R-C VALUES FOR FILTER CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RF1	4.4887	353.8692m	n/a
RF2	12.3836	590.0752m	n/a
RF3	30.9686	219.4408m	n/a
RF4	17.1592	536.6148m	n/a
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	4.6123m	43.6352u	n/a
CF2	78.5369m	785.6194u	n/a
CF3	841.9231m	13.4004u	n/a
CF4	7.2152	5.8633m	n/a

Note

- n/a indicates not applicable

